



**THE DATASHEET OF
NCP134AMX110TCG**



500 mA, Very Low Dropout Bias Rail CMOS Voltage Regulator

NCP134

The NCP134 is a 500 mA VLDO equipped with NMOS pass transistor and a separate bias supply voltage (V_{BIAS}). The device provides very stable, accurate output voltage with low noise suitable for space constrained, noise sensitive applications. In order to optimize performance for battery operated portable applications, the NCP134 features low I_Q consumption. The XDFN4 1.2 mm x 1.2 mm package is optimized for use in space constrained applications.

Features

- Input Voltage Range: 0.8 V to 5.5 V
- Bias Voltage Range: 2.4 V to 5.5 V
- Fixed Voltage Versions Available
- Output Voltage Range: 0.8 V to 2.1 V (Fixed)
- $\pm 1.5\%$ Accuracy over Temperature, $0.5\% V_{OUT}$ @ 25°C
- Ultra-Low Dropout: Max. 150 mV at 500 mA, 1.1 V Output, 3.3 V Bias, 85°C
- Very Low Bias Input Current of Typ. $80\ \mu\text{A}$
- Very Low Bias Input Current in Disable Mode: Typ. $0.5\ \mu\text{A}$
- Logic Level Enable Input for ON/OFF Control
- Output Active Discharge Option Available
- Stable with a $2.2\ \mu\text{F}$ Ceramic Capacitor
- Available in XDFN4 – 1.2 mm x 1.2 mm x 0.4 mm Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Battery-powered Equipment
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders

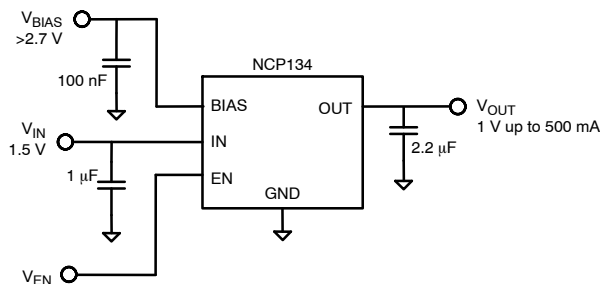
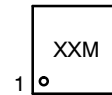


Figure 1. Typical Application Schematics



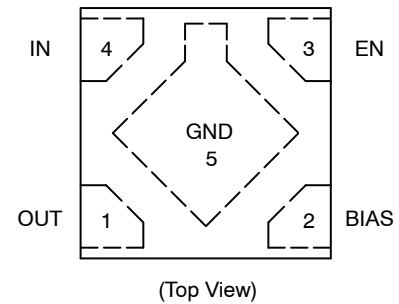
XDFN4
CASE 711BC

MARKING DIAGRAM



XX = Specific Device Code
M = Date Code

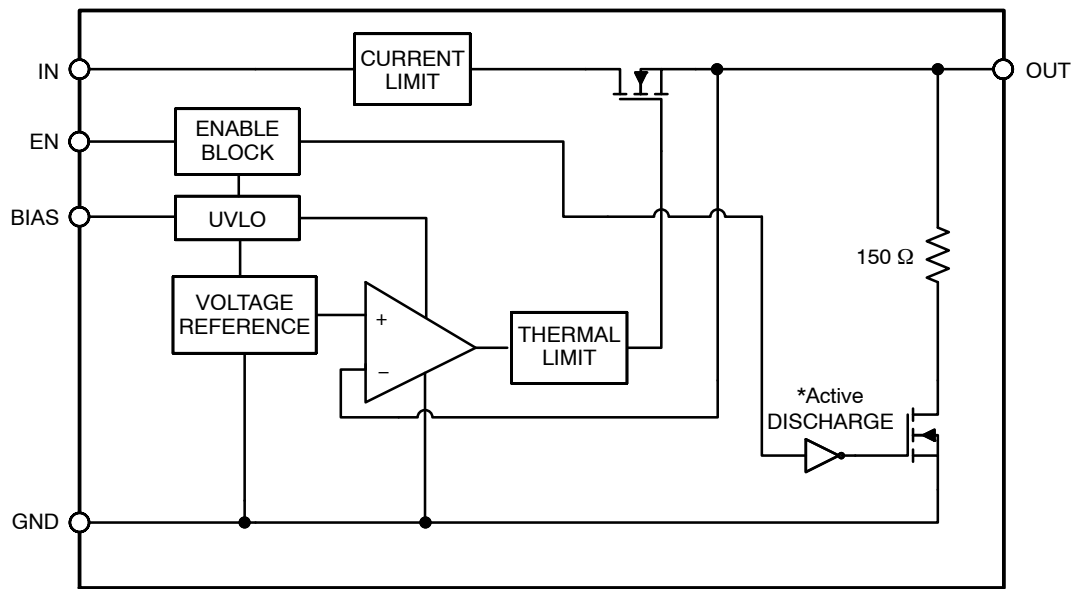
PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 10 of this data sheet.

NCP134



*Active output discharge function is present only in NCP134AMXyyyTCG devices.
yyy denotes the particular output voltage option.

Figure 2. Simplified Schematic Block Diagram – Fixed Version

NCP134

PIN FUNCTION DESCRIPTION

Pin No. XDFN4	Pin Name	Description
1	OUT	Regulated Output Voltage pin
2	BIAS	Bias voltage supply for internal control circuits. This pin is monitored by internal Under-Voltage Lockout Circuit.
3	EN	Enable pin. Driving this pin high enables the regulator. Driving this pin low puts the regulator into shutdown mode.
4	IN	Input Voltage Supply pin
5	GND	Ground

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V_{IN}	-0.3 to 6	V
Output Voltage	V_{OUT}	-0.3 to $(V_{IN}+0.3) \leq 6$	V
Chip Enable, Bias Input	V_{EN}, V_{BIAS}	-0.3 to 6	V
Output Short Circuit Duration	t_{SC}	unlimited	s
Maximum Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD_{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. This device series incorporates ESD protection (except OUT pin) and is tested by the following methods:
 ESD Human Body Model tested per EIA/JESD22-A114
 ESD Machine Model tested per EIA/JESD22-A115
 Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, XDFN4 1.2 mm x 1.2 mm Thermal Resistance, Junction-to-Air (Note 3)	$R_{\theta JA}$	170	°C/W

3. This data was derived by thermal simulations for a single device mounted on the 40 mm x 40 mm x 1.6 mm FR4 PCB with 2-ounce 800 sq mm copper area on top and bottom.

NCP134

ELECTRICAL CHARACTERISTICS $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$; $V_{\text{BIAS}} = 2.7\text{ V}$ or $(V_{\text{OUT}} + 1.6\text{ V})$, whichever is greater, $V_{\text{IN}} = V_{\text{OUT(NOM)}} + 0.3\text{ V}$, $I_{\text{OUT}} = 1\text{ mA}$, $V_{\text{EN}} = 1\text{ V}$, unless otherwise noted. $C_{\text{IN}} = 1\text{ }\mu\text{F}$, $C_{\text{OUT}} = 2.2\text{ }\mu\text{F}$. Typical values are at $T_J = +25^{\circ}\text{C}$. Min/Max values are for $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$ unless otherwise noted. (Note 4)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Operating Input Voltage Range		V_{IN}	$V_{\text{OUT}} + V_{\text{DO}}$		5.5	V
Operating Bias Voltage Range		V_{BIAS}	$(V_{\text{OUT}} + 1.40) \geq 2.4$		5.5	V
Undervoltage Lock-out	V_{BIAS} Rising Hysteresis	UVLO		1.6 0.2		V
Output Voltage Accuracy		V_{OUT}		± 0.5		%
Output Voltage Accuracy	$-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$, $V_{\text{OUT(NOM)}} + 0.3\text{ V} \leq V_{\text{IN}} \leq V_{\text{OUT(NOM)}} + 1.0\text{ V}$, 2.7 V or $(V_{\text{OUT(NOM)}} + 1.6\text{ V})$, whichever is greater $< V_{\text{BIAS}} < 5.5\text{ V}$, $1\text{ mA} < I_{\text{OUT}} < 500\text{ mA}$	V_{OUT}	-1.5		+1.5	%
V_{IN} Line Regulation	$V_{\text{OUT(NOM)}} + 0.3\text{ V} \leq V_{\text{IN}} \leq 5.0\text{ V}$	LineReg		0.01		%/V
V_{BIAS} Line Regulation	2.7 V or $(V_{\text{OUT(NOM)}} + 1.6\text{ V})$, whichever is greater $< V_{\text{BIAS}} < 5.5\text{ V}$	LineReg		0.01		%/V
Load Regulation	$I_{\text{OUT}} = 1\text{ mA}$ to 500 mA	LoadReg		1.5		mV
V_{IN} Dropout Voltage	$I_{\text{OUT}} = 150\text{ mA}$ (Note 5)	V_{DO}		37	75	mV
	$I_{\text{OUT}} = 500\text{ mA}$ (Note 5)	V_{DO}		140	250	
V_{IN} Dropout Voltage	NCP134AMX110TCG device, $V_{\text{OUT(NOM)}} = 1.1\text{ V}$, $V_{\text{BIAS}} = 3.3\text{ V}$, $I_{\text{OUT}} = 500\text{ mA}$ (Note 5)	V_{DO}		100	150	
V_{BIAS} Dropout Voltage	$I_{\text{OUT}} = 500\text{ mA}$, $V_{\text{IN}} = V_{\text{BIAS}}$ (Notes 5, 6)	V_{DO}		1.1	1.5	V
Output Current Limit	$V_{\text{OUT}} = 90\% V_{\text{OUT(NOM)}}$	I_{CL}	550	800	1000	mA
Bias Pin Operating Current	$V_{\text{BIAS}} = 2.7\text{ V}$	I_{BIAS}		80	110	μA
Bias Pin Disable Current	$V_{\text{EN}} \leq 0.4\text{ V}$	$I_{\text{BIAS(DIS)}}$		0.5	1	μA
Vinpin Pin Disable Current	$V_{\text{EN}} \leq 0.4\text{ V}$	$I_{\text{VIN(DIS)}}$		0.5	1	μA
EN Pin Threshold Voltage	EN Input Voltage "H"	$V_{\text{EN(H)}}$	0.9			V
	EN Input Voltage "L"	$V_{\text{EN(L)}}$			0.4	
EN Pull Down Current	$V_{\text{EN}} = 5.5\text{ V}$	I_{EN}		0.3	1	μA
Turn-On Time	From assertion of V_{EN} to $V_{\text{OUT}} = 98\% V_{\text{OUT(NOM)}}$. $V_{\text{OUT(NOM)}} = 1.0\text{ V}$	t_{ON}		150		μs
Power Supply Rejection Ratio	V_{IN} to V_{OUT} , $f = 1\text{ kHz}$, $I_{\text{OUT}} = 150\text{ mA}$, $V_{\text{IN}} \geq V_{\text{OUT}} + 0.5\text{ V}$	PSRR(V_{IN})		70		dB
	V_{BIAS} to V_{OUT} , $f = 1\text{ kHz}$, $I_{\text{OUT}} = 150\text{ mA}$, $V_{\text{IN}} \geq V_{\text{OUT}} + 0.5\text{ V}$	PSRR(V_{BIAS})		80		
Output Noise Voltage	$V_{\text{IN}} = V_{\text{OUT}} + 0.5\text{ V}$, $V_{\text{OUT(NOM)}} = 1\text{ V}$, $f = 10\text{ Hz}$ to 100 kHz	V_{N}		40		μV_{RMS}
Thermal Shutdown Threshold	Temperature increasing			160		$^{\circ}\text{C}$
	Temperature decreasing			140		
Output Discharge Pull-Down	$V_{\text{EN}} \leq 0.4\text{ V}$, $V_{\text{OUT}} = 0.5\text{ V}$, NCP134A options only	R_{DISCH}		150		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at $T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible.
5. Dropout voltage is characterized when V_{OUT} falls 3% below $V_{\text{OUT(NOM)}}$.
6. For output voltages below 0.9 V , V_{BIAS} dropout voltage does not apply due to a minimum Bias operating voltage of 2.4 V .

TYPICAL CHARACTERISTICS

AT $T_J = +25^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$, $V_{BIAS} = 2.7\text{ V}$, $V_{EN} = V_{BIAS}$, $V_{OUT(NOM)} = 1.0\text{ V}$, $I_{OUT} = 500\text{ mA}$, $C_{IN} = 1\text{ MF}$, $C_{BIAS} = 0.1\text{ MF}$, AND $C_{OUT} = 2.2\text{ MF}$ (EFFECTIVE CAPACITANCE), UNLESS OTHERWISE NOTED.

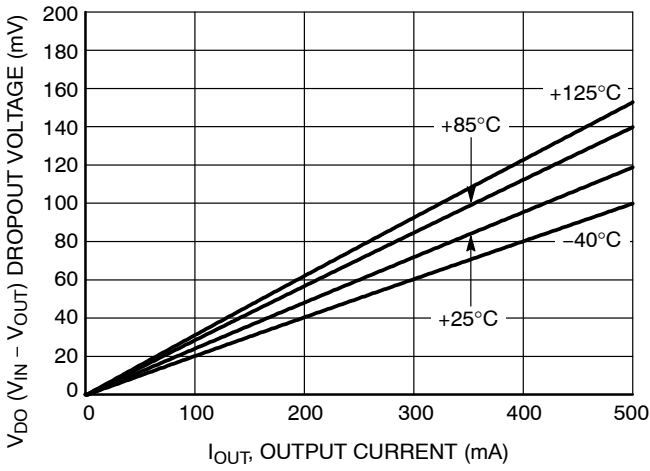


Figure 3. V_{IN} Dropout Voltage vs. I_{OUT} and Temperature T_J

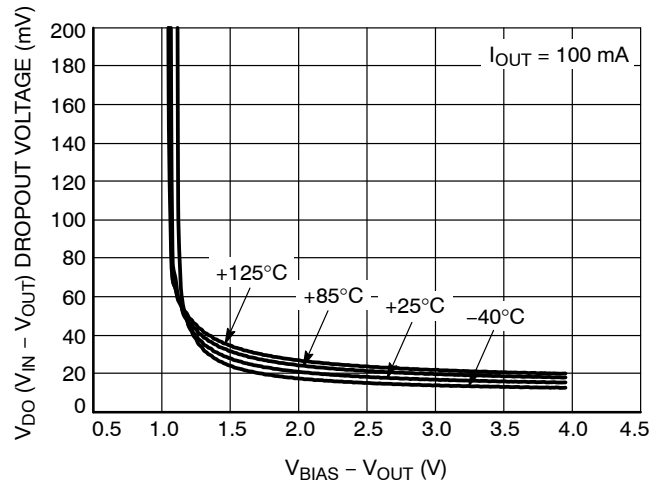


Figure 4. V_{IN} Dropout Voltage vs. $(V_{BIAS} - V_{OUT})$ and Temperature T_J

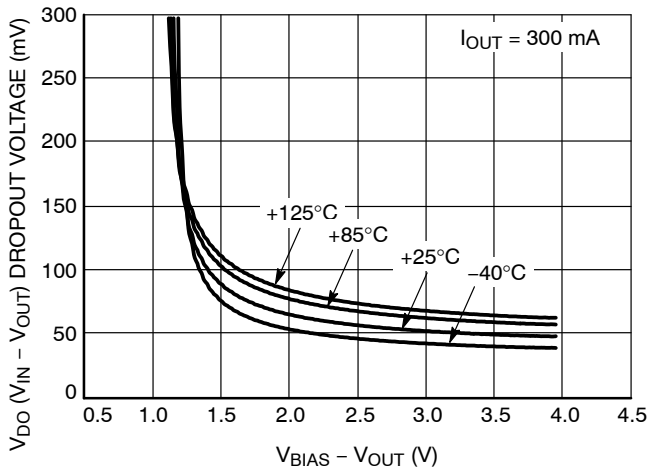


Figure 5. V_{IN} Dropout Voltage vs. $(V_{BIAS} - V_{OUT})$ and Temperature T_J

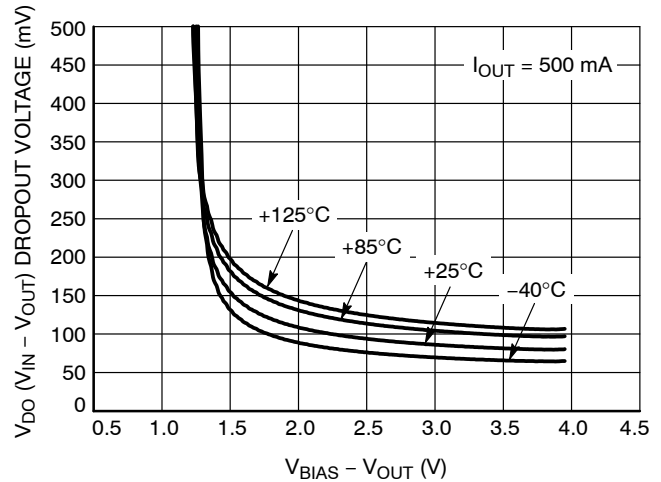


Figure 6. V_{IN} Dropout Voltage vs. $(V_{BIAS} - V_{OUT})$ and Temperature T_J

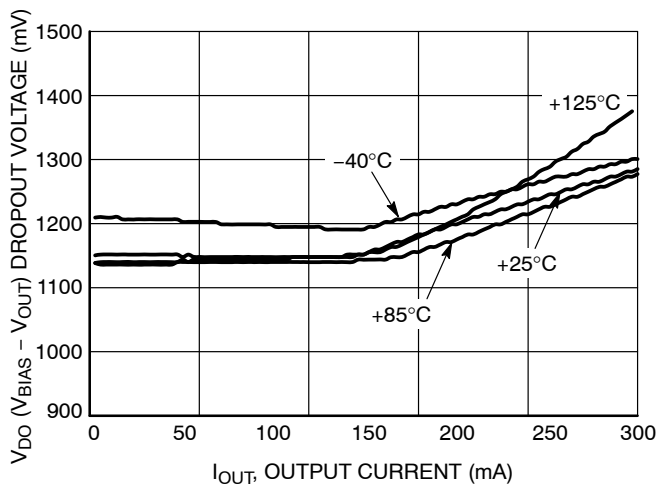


Figure 7. V_{BIAS} Dropout Voltage vs. I_{OUT} and Temperature T_J

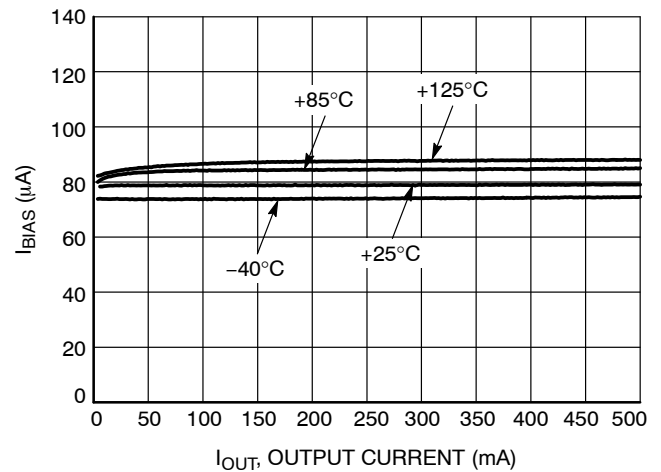


Figure 8. BIAS Pin Current vs. I_{OUT} and Temperature T_J

NCP134

TYPICAL CHARACTERISTICS (continued)

AT $T_J = +25^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$, $V_{BIAS} = 2.7\text{ V}$, $V_{EN} = V_{BIAS}$, $V_{OUT(NOM)} = 1.0\text{ V}$, $I_{OUT} = 500\text{ mA}$, $C_{IN} = 1\text{ MF}$, $C_{BIAS} = 0.1\text{ MF}$, AND $C_{OUT} = 2.2\text{ MF}$ (EFFECTIVE CAPACITANCE), UNLESS OTHERWISE NOTED.

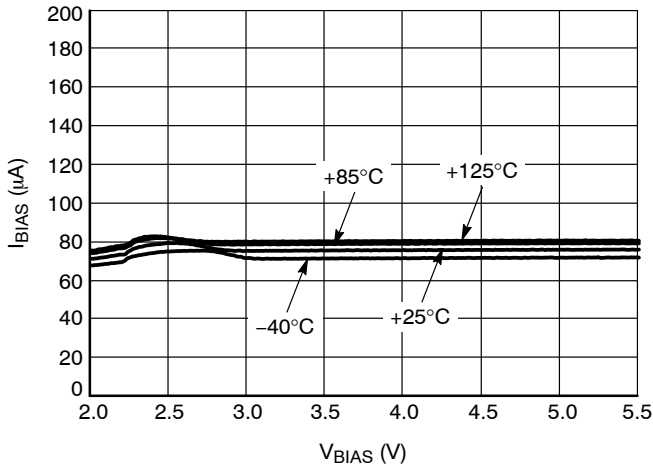


Figure 9. BIAS Pin Current vs. V_{BIAS} and Temperature T_J

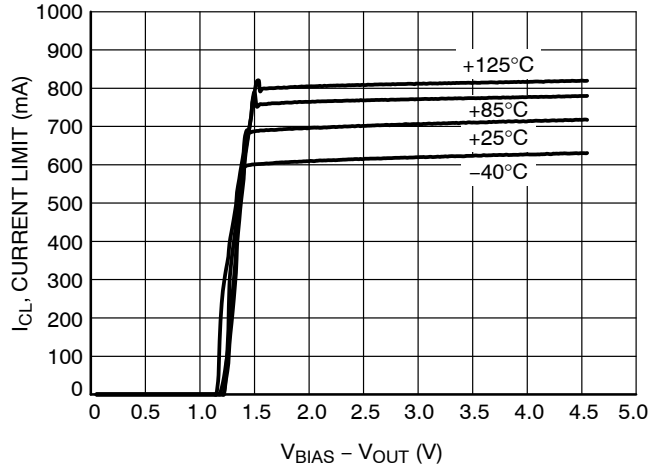


Figure 10. Current Limit vs. $(V_{BIAS} - V_{OUT})$

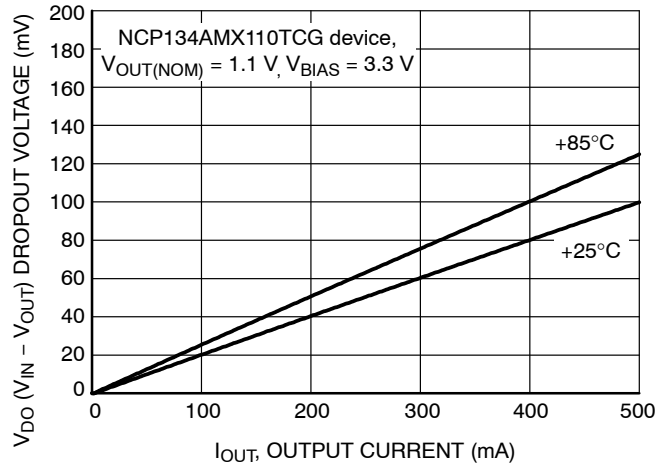


Figure 11. V_{IN} Dropout Voltage vs. I_{OUT} and Temperature T_J

NCP134

TYPICAL CHARACTERISTICS (continued)

AT $T_J = +25^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$, $V_{BIAS} = 2.7\text{ V}$, $V_{EN} = V_{BIAS}$, $V_{OUT(NOM)} = 1.0\text{ V}$, $I_{OUT} = 500\text{ mA}$, $C_{IN} = 1\text{ MF}$, $C_{BIAS} = 0.1\text{ MF}$, AND $C_{OUT} = 2.2\text{ MF}$ (EFFECTIVE CAPACITANCE), UNLESS OTHERWISE NOTED.

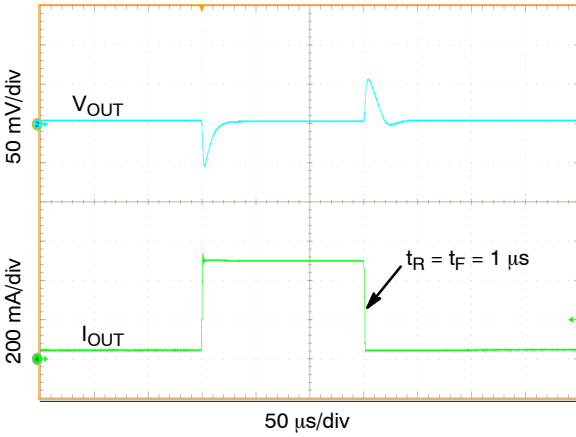


Figure 12. Load Transient Response, $I_{OUT} = 50\text{ mA}$ to 500 mA , $C_{OUT} = 10\text{ }\mu\text{F}$

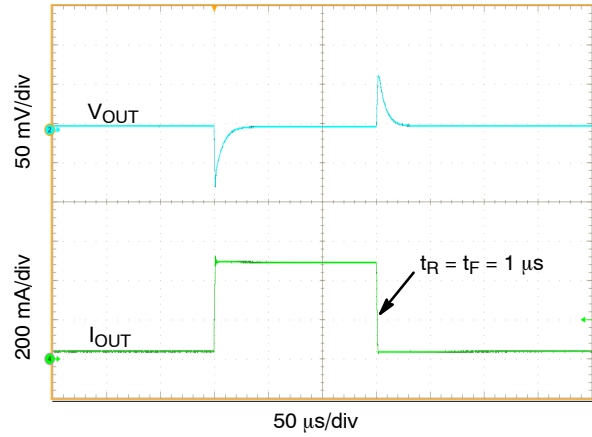


Figure 13. Load Transient Response, $I_{OUT} = 50\text{ mA}$ to 500 mA , $C_{OUT} = 2.2\text{ }\mu\text{F}$

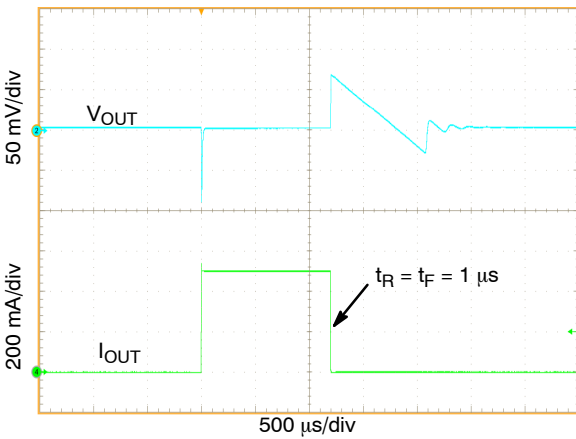


Figure 14. Load Transient Response, $I_{OUT} = 1\text{ mA}$ to 500 mA , $C_{OUT} = 10\text{ }\mu\text{F}$

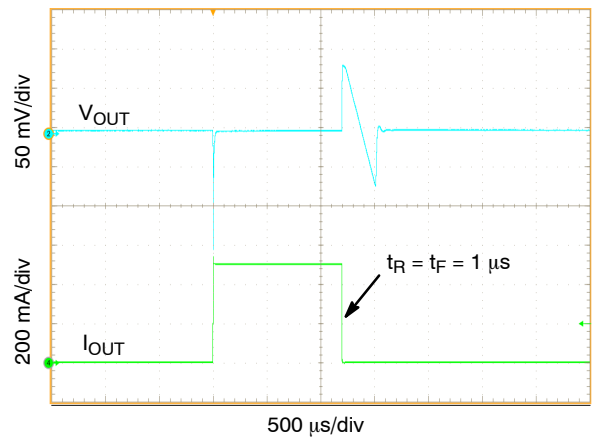


Figure 15. Load Transient Response, $I_{OUT} = 1\text{ mA}$ to 500 mA , $C_{OUT} = 2.2\text{ }\mu\text{F}$

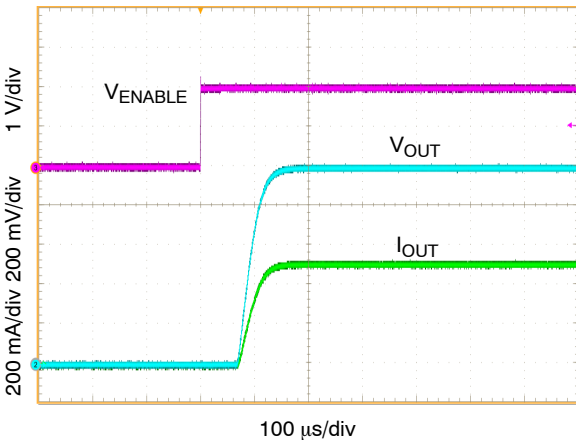


Figure 16. Enable Turn-on Response, Output Resistive Load 500 mA , $C_{OUT} = 10\text{ }\mu\text{F}$

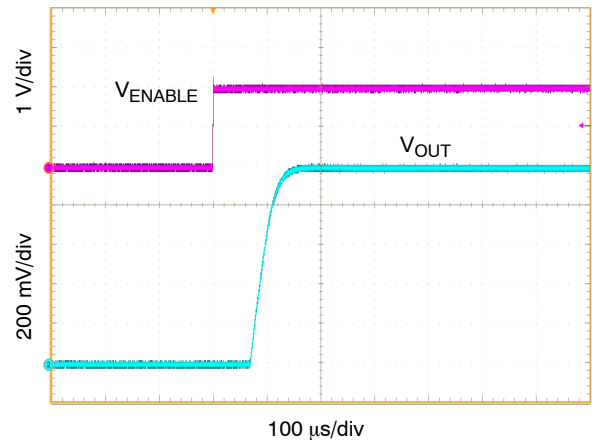


Figure 17. Enable Turn-on Response, $I_{OUT} = 0\text{ mA}$, $C_{OUT} = 2.2\text{ }\mu\text{F}$

NCP134

TYPICAL CHARACTERISTICS (continued)

AT $T_J = +25^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$, $V_{BIAS} = 2.7\text{ V}$, $V_{EN} = V_{BIAS}$, $V_{OUT(NOM)} = 1.0\text{ V}$, $I_{OUT} = 500\text{ mA}$, $C_{IN} = 1\text{ MF}$, $C_{BIAS} = 0.1\text{ MF}$, AND $C_{OUT} = 2.2\text{ MF}$ (EFFECTIVE CAPACITANCE), UNLESS OTHERWISE NOTED.

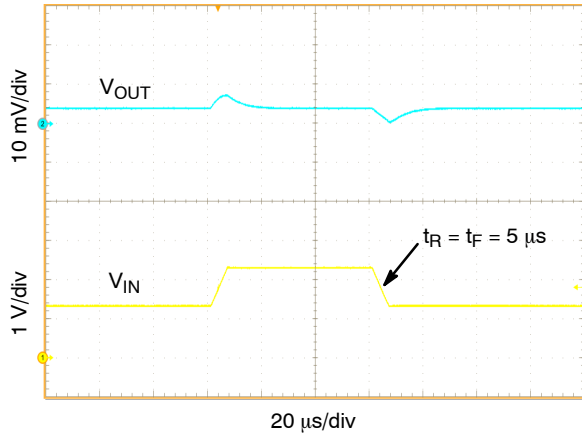


Figure 18. V_{IN} Line Transient Response,
 $V_{IN} = 1.3\text{ V to } 2.3\text{ V}$, $I_{OUT} = 100\text{ mA}$, $C_{OUT} = 10\ \mu\text{F}$

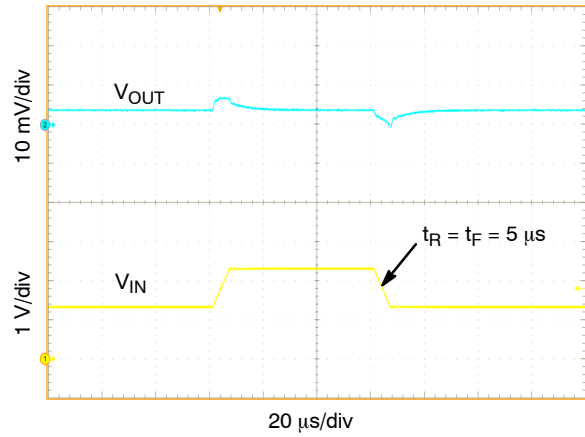


Figure 19. V_{IN} Line Transient Response,
 $V_{IN} = 1.3\text{ V to } 2.3\text{ V}$, $I_{OUT} = 100\text{ mA}$, $C_{OUT} = 2.2\ \mu\text{F}$

APPLICATIONS INFORMATION

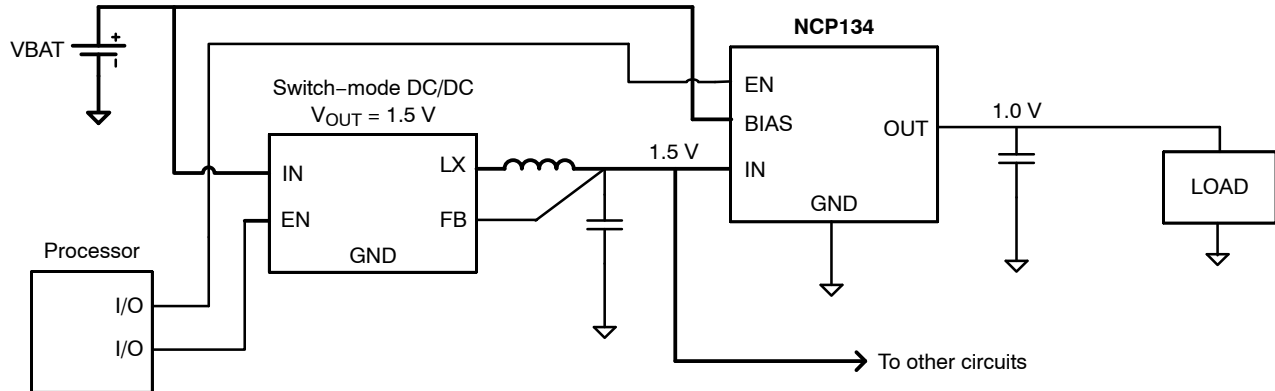


Figure 20. Typical Application: Low-Voltage DC/DC Post-Regulator with ON/OFF Functionality

The NCP134 dual-rail very low dropout voltage regulator is using NMOS pass transistor for output voltage regulation from V_{IN} voltage. All the low current internal control circuitry is powered from the V_{BIAS} voltage.

The use of an NMOS pass transistor offers several advantages in applications. Unlike PMOS topology devices, the output capacitor has reduced impact on loop stability. V_{in} to V_{out} operating voltage difference can be very low compared with standard PMOS regulators in very low V_{in} applications.

The NCP134 offers smooth monotonic start-up. The controlled voltage rising limits the inrush current.

The Enable (EN) input is equipped with internal hysteresis. NCP134 Voltage linear regulator Fixed version is available.

Dropout Voltage

Because of two power supply inputs V_{IN} and V_{BIAS} and one V_{OUT} regulator output, there are two Dropout voltages specified.

The first, the V_{IN} Dropout voltage is the voltage difference ($V_{IN} - V_{OUT}$) when V_{OUT} starts to decrease by percent specified in the Electrical Characteristics table. V_{BIAS} is high enough; specific value is published in the Electrical Characteristics table.

The second, V_{BIAS} dropout voltage is the voltage difference ($V_{BIAS} - V_{OUT}$) when V_{IN} and V_{BIAS} pins are joined together and V_{OUT} starts to decrease.

Input and Output Capacitors

The device is designed to be stable for ceramic output capacitors with Effective capacitance in the range from 2.2 μF to 10 μF . The device is also stable with multiple capacitors in parallel, having the total effective capacitance in the specified range.

In applications where no low input supplies impedance available (PCB inductance in V_{IN} and/or V_{BIAS} inputs as example), the recommended $C_{IN} = 1 \mu\text{F}$ and $C_{BIAS} = 0.1 \mu\text{F}$

or greater. Ceramic capacitors are recommended. For the best performance all the capacitors should be connected to the NCP134 respective pins directly in the device PCB copper layer, not through vias having not negligible impedance.

When using small ceramic capacitor, their capacitance is not constant but varies with applied DC biasing voltage, temperature and tolerance. The effective capacitance can be much lower than their nominal capacitance value, most importantly in negative temperatures and higher LDO output voltages. That is why the recommended Output capacitor capacitance value is specified as Effective value in the specific application conditions.

Enable Operation

The enable pin will turn the regulator on or off. The threshold limits are covered in the electrical characteristics table in this data sheet. If the enable function is not to be used then the pin should be connected to V_{IN} or V_{BIAS} .

Current Limitation

The internal Current Limitation circuitry allows the device to supply the full nominal current and surges but protects the device against Current Overload or Short.

Thermal Protection

Internal thermal shutdown (TSD) circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When TSD activated, the regulator output turns off. When cooling down under the low temperature threshold, device output is activated again. This TSD feature is provided to prevent failures from accidental overheating.

Activation of the thermal protection circuit indicates excessive power dissipation or inadequate heatsinking. For reliable operation, junction temperature should be limited to +125°C maximum.

NCP134

ORDERING INFORMATION

Device	Nominal Output Voltage	Marking	Option	Package	Shipping†
NCP134AMX080TCG	0.80 V	GG	Output Active Discharge	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP134AMX085TCG	0.85 V	GL	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)
NCP134AMX090TCG	0.90 V	GF	Output Active Discharge	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP134AMX100TCG	1.00 V	GA	Output Active Discharge	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP134AMX105TCG	1.05 V	GC	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)
NCP134AMX110TCG	1.10 V	GD	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)
NCP134AMX120TCG	1.20 V	GE	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)
NCP134AMX135TCG	1.35 V	GJ	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)
NCP134AMX150TCG	1.50 V	GH	Output Active Discharge	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP134AMX180TCG	1.80 V	GK	Output Active Discharge	XDFN4 (Pb-Free)	3000 or 5000 / Tape & Reel (Note 7)

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

To order other package and voltage variants, please contact your **onsemi** sales representative

7. Product processed after October 1, 2022 are shipped with quantity 5000 units / Tape & Reel.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

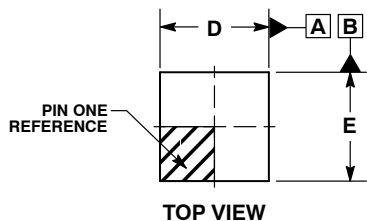
ON Semiconductor®



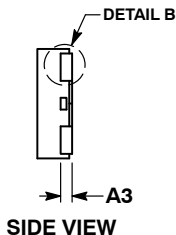
SCALE 4:1

XDFN4 1.2x1.2, 0.8P
CASE 711BC
ISSUE O

DATE 15 SEP 2015



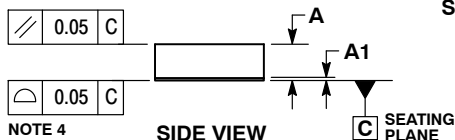
TOP VIEW



SIDE VIEW

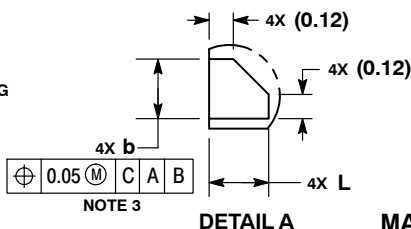


DETAIL B
ALTERNATE
CONSTRUCTION



SIDE VIEW

NOTE 4



DETAIL A

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 mm FROM THE TERMINAL TIPS.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

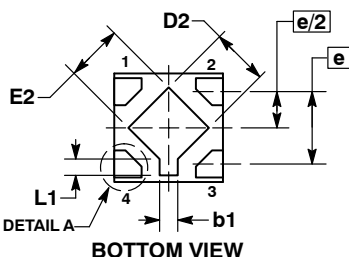
MILLIMETERS		
DIM	MIN	MAX
A	0.35	0.45
A1	0.00	0.05
A3	0.13	REF
b	0.25	0.35
b1	0.15	0.25
D	1.15	1.25
D2	0.58	0.68
E	1.15	1.25
E2	0.58	0.68
e	0.80	BSC
L	0.25	0.35
L1	0.13	0.23

GENERIC MARKING DIAGRAM*



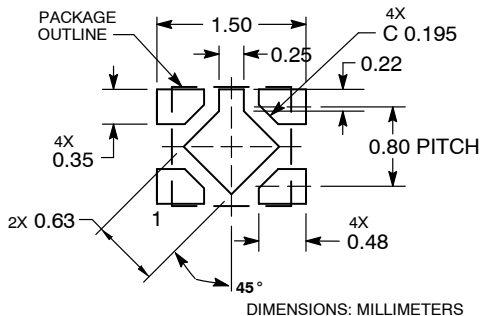
XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "▪", may or may not be present.



BOTTOM VIEW

RECOMMENDED MOUNTING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON04908G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	XDFN4, 1.2X1.2, 0.8P	PAGE 1 OF 1

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View NCP134AMX110TCG on WIN SOURCE](#)
- ⊖ [ON Semiconductor Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management